

Remarks:

This preliminary amendment is being submitted in an effort to correct a typographical error in claim 8. No new matter has been added. The changes are not made for any reason related to the statutory requirements for a patent nor do they narrow the scope of the claim for any reason related to the statutory requirements for a patent.

An early action on the merits of the application is solicited.

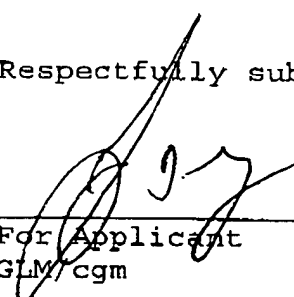
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Please charge any fees that might be due with respect to Sections 1.16 and 1.17 to the Deposit Account of Lerner and Greenberg, P.A., No. 12-1099.

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15 Respectfully submitted,

  
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20 For Applicant  
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Marked-up Version of Claims to Show Changes Made:

Claim 8 (amended). The method according to claim [5]7, which further comprises choosing the magnitude of the doping of the further buffer layer such that, in an operating state in which the semiconductor component effects blocking in the direction from the drain contact toward the source contact, at least in an envisaged range of applied electrical voltages, a space charge zone present in the first base region is formed in a manner extending at least as far as the further buffer layer.

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